



Selling Points

- Easy operation and compact design
- Auto-measurement start by inserting a wafer under the probe
- Easy set up to measurement condition by JOG dial
- 5 types of model for each measuring range

Details

Applications

- Semiconductor materials, Solar-cell materials (Silicon, Polysilicon, SiC etc)
- New materials, functional materials (Carbon nanotube, DLC, graphene, Ag nanowire etc)
- Conductive thin film (Metal, ITO etc)
- Silicon-related epitaxial materials, Ion-implantation sample
- Chemical compound semiconductor (GaAs Epi, GaN Epi, InP, Ga etc)
- Others (*Please contact us for details)

Sample sizes

~8 inch, ~156x156mm

Measuring range

[R] 1m ~ 200 Ω·cm [RS] 10m ~ 3,000 Ω/sq

* The range is separated from each Low, Middle, High and S-High probe type.

*Please refer the measurement range for each probe type as below;

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|--------------------------------------|--------------------------------------|
| ①Low : 0.01~0.5Ω/sq (0.001~0.05Ω·cm) | ③High : 10~1000Ω/sq (0.5~60Ω·cm) |
| ②Middle : 0.5~10Ω/sq (0.05~0.5Ω·cm) | ④S-High : 1000~3000Ω/sq (60~200Ω·cm) |

